



High Intensity SMD LED

Description

This device has been designed to meet the increasing demand for white SMD LED.

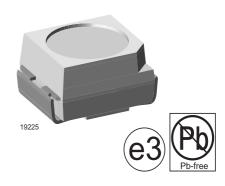
The package of the TLMW310. is the PLCC-2 (equivalent to a size B tantalum capacitor).

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled with a mixture of epoxy and TAG phosphor.

The TAG phosphor converts the blue emission partially to yellow, which mixes with the remaining blue to give white.

Features

- · High efficient InGaN technology
- Chromaticity Coordinate categorized according to CIE1931 per packing unit
- Luminous intensity ratio in one packing unit $I_{Vmax}/I_{Vmin} \le 1.6$
- Typical color temperature 5500 K
- ESD class 1
- · EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC
- · Available in 8 mm tape reel
- · Lead-free device



Applications

Automotive: Backlighting in dashboards and switches Telecommunication: Indicator and backlighting in telephone and fax

Backlighting for audio and video equipment

Backlighting in office equipment

Indoor and outdoor message boards

Flat backlight for LCDs, switches and symbols

Illumination purposes, alternative to incandescent lamps

General use

Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity (±φ)	Technology
TLMW3100	White, I _V > 80 mcd	60 °	InGaN / TAG on SiC
TLMW3101	White, I _V = (80 to 200) mcd	60 °	InGaN / TAG on SiC
TLMW3102	White, $I_V = (125 \text{ to } 320) \text{ mcd}$	60 °	InGaN / TAG on SiC

Absolute Maximum Ratings

 $T_{amb} = 25 \, ^{\circ}\text{C}$, unless otherwise specified **TLMW310**.

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V _R	5	V
DC Forward current	T _{amb} ≤ 70 °C	I _F	20	mA
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.1	Α
Power dissipation	T _{amb} ≤ 70 °C	P _V	85	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C

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Parameter	Test condition	Symbol	Value	Unit
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C
Thermal resistance junction/ ambient	mounted on PC board (pad size > 16 mm ²)	R _{thJA}	350	K/W

Optical and Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

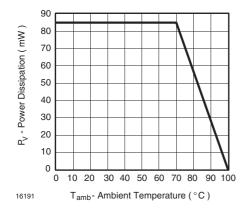
White

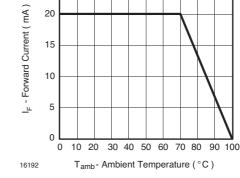
TLMW310.

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity 1)	I _F = 20 mA	TLMW3100	I _V	80	140		mcd
		TLMW3101	I _V	80		200	mcd
		TLMW3102	I _V	125		320	mcd
Chromaticity coordinate x acc. to CIE 1931	I _F = 20 mA	TLMW3100	х		0.33		
Chromaticity coordinate y acc. to CIE 1931	I _F = 20 mA	TLMW3100	у		0.33		
Angle of half intensity	I _F = 20 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V _F		3.5	4.2	V
Reverse voltage	I _R = 10 μA		V _R	5			V
Temperature coefficient of V _F	I _F = 20 mA		TC _{VF}		- 4		mV/K
Temperature coefficient of I _V	I _F = 20 mA		TC _{IV}		- 0.5		% / K

¹⁾ in one Packing Unit $I_{Vmax}/I_{Vmin} \le 1.6$

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)





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Figure 1. Power Dissipation vs. Ambient Temperature

Figure 2. Forward Current vs. Ambient Temperature for AllnGaP

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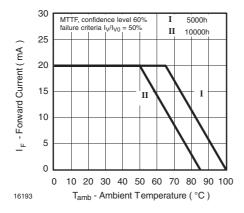


Figure 3. Forward Current vs. Ambient Temperature for AllnGaP

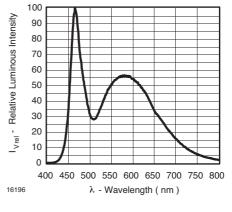


Figure 6. Relative Intensity vs. Wavelength

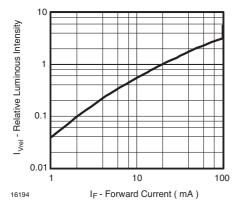


Figure 4. Relative Luminous Intensity vs. Forward Current

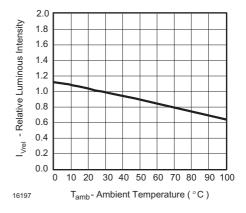


Figure 7. Rel. Luminous Intensity vs. Ambient Temperature

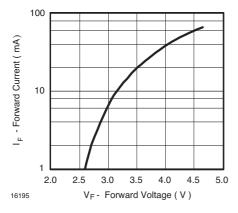


Figure 5. Forward Current vs. Forward Voltage

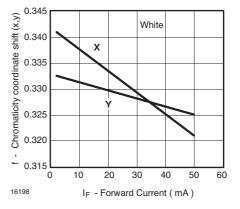


Figure 8. Chromaticity Coordinate Shift vs. Forward Current

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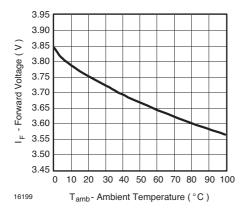


Figure 9. Forward Voltage vs. Ambient Temperature

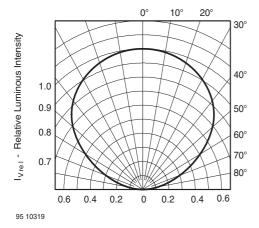


Figure 10. Rel. Luminous Intensity vs. Angular Displacement

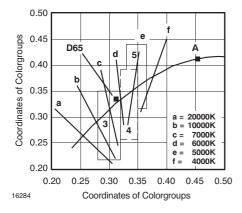


Figure 11. Coordinates of Colorgroups

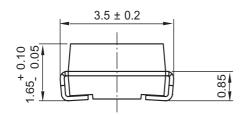
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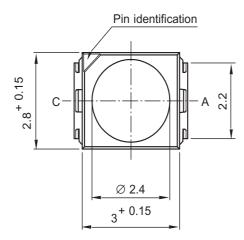


Package Dimensions in mm





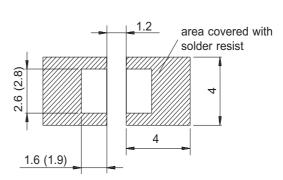
Mounting Pad Layout



Drawing-No.: 6.541-5025.01-4

Issue: 7; 05.04.04

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Dimensions: IR and Vaporphase (Wave Soldering)



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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